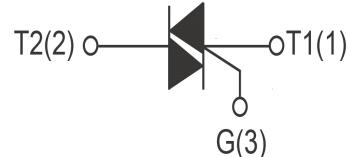


3 Quadrants TRIAC

4 Quadrants TRIAC

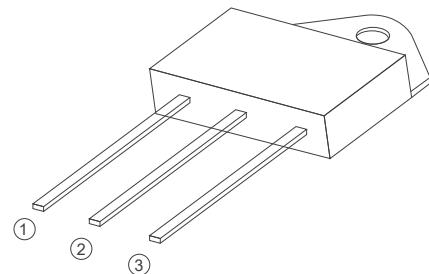
FEATURES

- > IT(RMS): 40A > VGT: <1.5V
- > VDRM VRMM:800V~1600V



APPLICATIONS

Washing machine, vacuums, massager, solid state relay,
AC Motor speed regulation and so on.



TO-3P

Absolute Maximum Ratings ($T_j=25^\circ\text{C}$ unless otherwise specified)

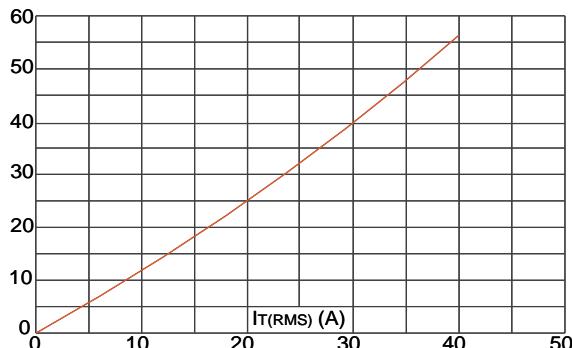
Symbol	Parameter	Conditions	Ratings	Unit
VDRM VRMM	Repetitive Peak Off-State Voltage	BTA41-800B	800	V
		BTA41-1200B	1200	
		BTA41-1600B	1600	
IT(RMS)	R.M.S On-State Current	$T_c=110^\circ\text{C}$	40	A
ITSM	Surge On-State Current	$t_p=16.7\text{ms}/t_p=10\text{ms}$	400/420	
I^2t	I^2t for fusing	$T_p=10\text{ms}$	520	A^2s
PG(AV)	Average Gate Power Dissipation	$T_j=125^\circ\text{C}$	1	W
IGM	Peak Gate Current	$T_j=125^\circ\text{C}$	8	A
T_j	Operating Junction Temperature		$\sim 40\text{~}\sim 125$	$^\circ\text{C}$
TSTG	Storage Temperature		$\sim 40\text{~}\sim 150$	

Electrical Characteristics (T_j=25°C unless otherwise specified)

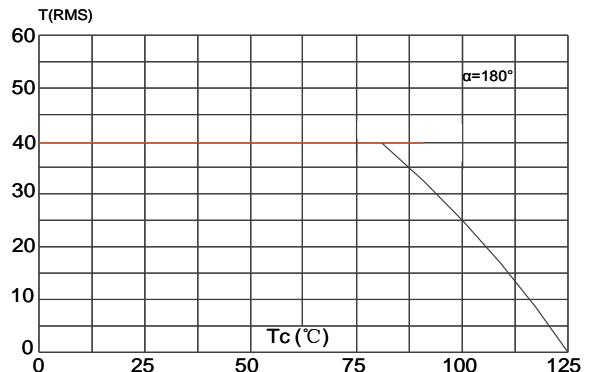
Symbol	Parameter	Test Conditions	BW	B	Unit
IDRM	Repetitive Peak Off-State Current	T _j =25°C	5		uA
		T _c =125°C	5		mA
IRRM	Repetitive Peak Reverse Current	T _c =25°C	5		uA
		T _c =125°C	5		mA
VTM	Forward "on" voltage	IT=23A, tp=380us	1.55		V
VGT	Gate trigger voltage	VD=12V, RL=30Ω	≤1.5		V
di/dt	VD=2/3VDRM Gate Open, T _j =125°C I,II,III,IV	F=100Hz, IG=2xIGT, tr≤100ns	50		A/us
IGT	Gate trigger current	I,II,III IV	VD=12V, RL=30Ω	≤50	≤50
				/	≤100
IH	Holding current	IT=0.2A	≤60	≤80	mA
VGD	Gate non-trigger voltage	VD=VDRM, TJ=125°C, RL=3.3KΩ	0.2		
dv/dt	Critical-rate of rise of commutation voltage	T _j =125°C, VD=2/3VDRM, Gate open circuit	≥1500	≥1000	V/us

FIG1

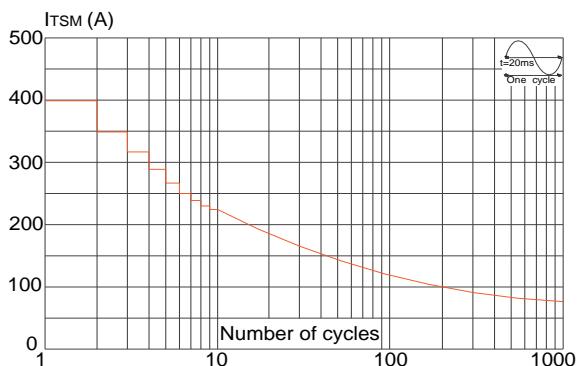
Maximum power dissipation versus RMS on-state current


FIG2

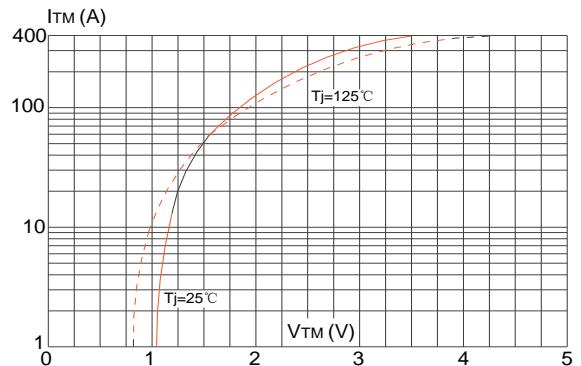
RMS on-state current versus case temperature


FIG3

Surge peak on-state current versus number of cycles


FIG4

On-state characteristics (maximum values)


FIG5

Non-repetitive surge peak on-state current for a sinusoidal pulse with width $tp < 20ms$, and corresponding value of I^2t ($dl/dt < 100A/\mu s$)

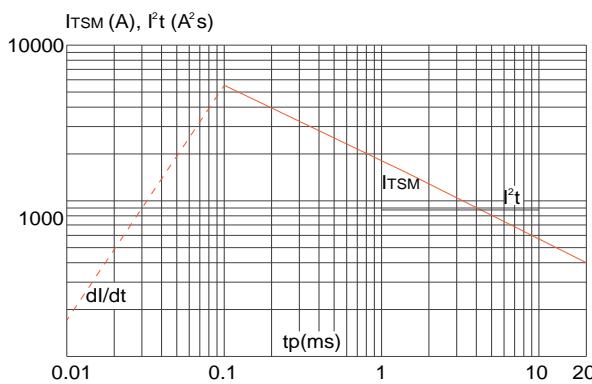
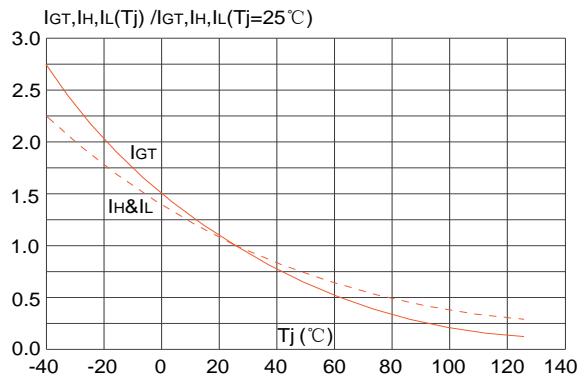
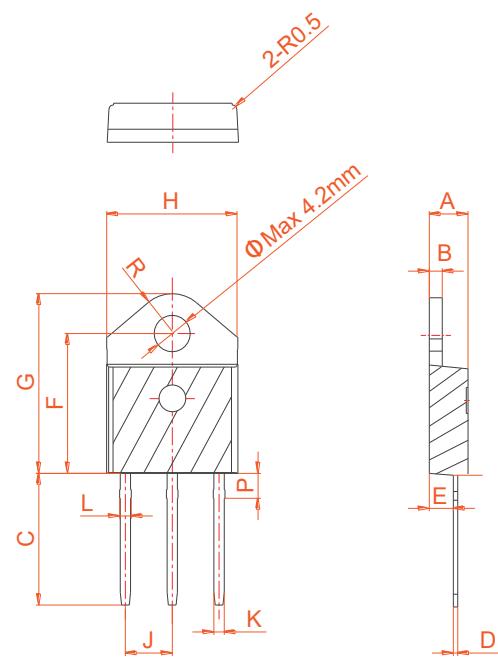

FIG6

FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature



PACKAGE MECHANICAL DATA

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	1.45		1.55	0.057		0.061
C	14.35		15.60	0.565		0.614
D	0.50		0.70	0.020		0.028
E	2.70		2.90	0.106		0.114
F	15.80		16.50	0.622		0.650
G	20.40		21.10	0.803		0.831
H	15.10		15.50	0.594		0.610
J	5.40		5.65	0.213		0.222
K	1.10		1.40	0.043		0.055
L	1.35		1.50	0.053		0.059
P	2.80		3.00	0.110		0.118
R		4.35			0.171	



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